

No.2297A

2 S C 3 7 8 4

NPN Epitaxial Planar Type Silicon Transistor

DRIVER APPLICATIONS

Applications

. Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers)

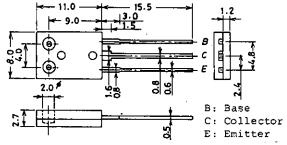
Features

- . High DC current gain
- . Wide ASO
- . On-chip zener diode of $60\pm10\text{V}$ between collector and base
- . Uniformity in collector to base breakdown voltage
- . Large inductive load handling capability

Absolute Maximum Ratings at T				unit			
Collector to Base Voltage	V _{CBO}			# 50	V		
Collector to Emitter Voltage	e V _{CEO}			# 50	V		
Emitter to Base Voltage	VEBO			6	V		
Collector Current	IC			1.2			
Peak Collector Current				2.5			*
Collector Dissipation	i Po			1.2			
The state of the s	P _C P _C	Tc=25 ^O C		20			
Junction Temperature	TÇ Tj	10-25 0			Δ		
Storage Temperature	-		EE 4.	150	oC.		
*: On-chip zener diode (60±	Tstg		oo to	+150	- C		
on-chip zener diode (00-	104)						
Electrical Characteristics at	Ta=25°C			min	typ	max	unit
Collector Cutoff Current I,	СВО	$V_{CB}=40V,I_{E}=0$			- • •	10	uA
	EBO	$V_{EB}^{CB}=5V, I_{C}=0$				10	mA
	edu Fe	V _{CE} =5V, I _C =500mA		1000	4000		
Gain-Bandwidth Product f.	re	V _{CE} =5V, I _C =500mA		.000	180		MHz
	T	I _C =500mA,I _B =2mA			1.0	1.5	V
	CE(sat)	I _C =500mA, I _B =2mA			7.0		-
Inductive Load E	BE(sat)	I - 100mH B - 100cl		. 45		2.0	ν
Handling Capability	5/0	L=100mH, R _{BE} =100ol		15			mJ
		T = 100m					
	(BR)CBO	I_{C} =100uA, I_{E} =0 I_{C} =1mA, R_{BE} = ∞		50	60	70	V
C-E Breakdown Voltage V	(DIV) CDO	- C 44 . 5 E		50	60	70	V

Package Dimensions 2043A

(unit: mm)



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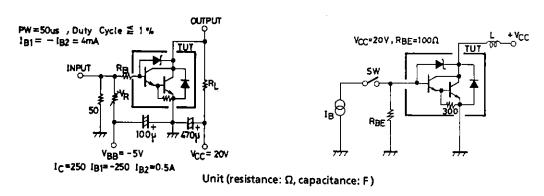
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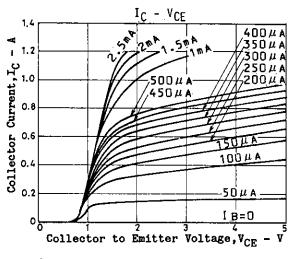
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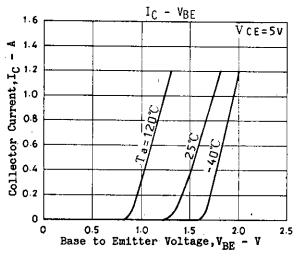
			min	tур	max	unit
Turn-on Time	t_{on}	See specified Test Circuit.		0.2		us
Storage Time	tstg	Ħ		2.2		us
Fall Time	$t_{\mathbf{f}}^{stg}$	u		0.4		us

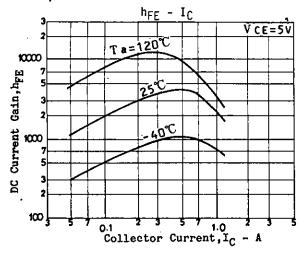
Switching Time Test Circuit

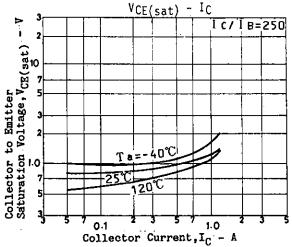
Es/b Test Circuit

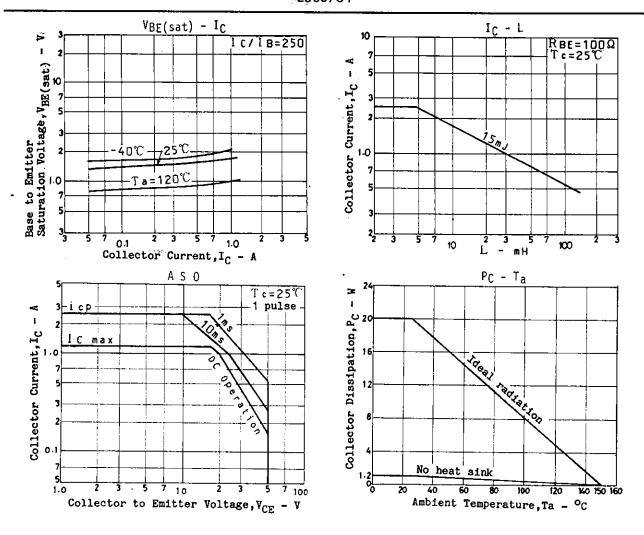












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